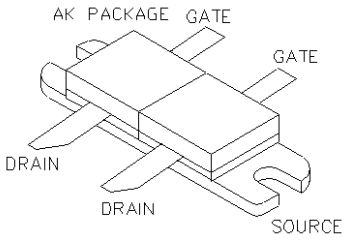
polyfet rf devices

SK723

General Description

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"^{TM} process features low feedback and output capacitances, resulting in high F_t transistors with high input impedance and high efficiency.



SILICON GATE ENHANCEMENT MODE

RF POWER VDMOS TRANSISTOR

50.0 Watts Push - Pull

Package Style AK

HIGH EFFICIENCY, LINEAR

HIGH GAIN, LOW NOISE

ROHS COMPLIANT

ABSOLUTE MAXIMUM RATINGS (T = 25 ^{o}C)

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
270 Watts	0.65 ^{o}C/W	200 ^{o}C	-65 ^{o}C to 150 ^{o}C	27.0 A	36 V	36 V	20 V

RF CHARACTERISTICS (50.0 WATTS OUTPUT)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	Idq = 1.20 A, Vds = 12.5 V, F = 400 MHz
η	Drain Efficiency		55		%	Idq = 1.20 A, Vds = 12.5 V, F = 400 MHz
VSWR	Load Mismatch Tolerance			20:1	Relative	Idq = 1.20 A, Vds = 12.5 V, F = 400 MHz

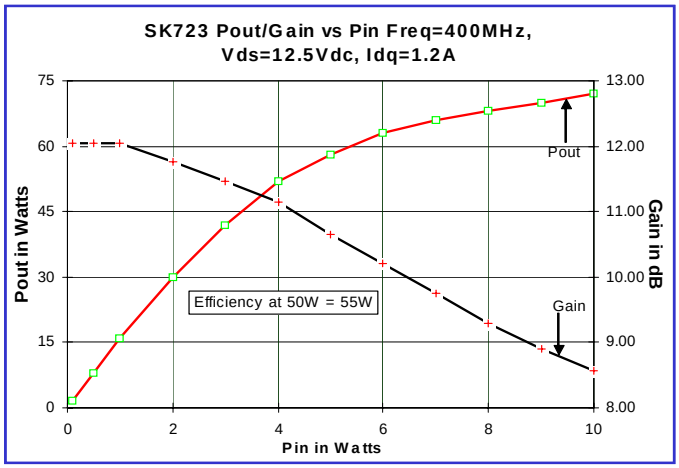
ELECTRICAL CHARACTERISTICS (EACH SIDE)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	36			V	Ids = 60.00 mA, Vgs = 0V
Idss	Zero Bias Drain Current			3.0	mA	Vds = 12.5 V, Vgs = 0V
Igss	Gate Leakage Current			1	uA	Vds = 0V Vgs = 30V
Vgs	Gate Bias for Drain Current	2		5	V	Ids = 0.30 A, Vgs = Vds
gM	Forward Transconductance		3.9		Mho	Vds = 10V, Vgs = 5V
Rdson	Saturation Resistance		0.25		Ohm	Vgs = 20V, Ids = 7.50 A
Idsat	Saturation Current		28.50		Amp	Vgs = 20V, Vds = 10V
Ciss	Common Source Input Capacitance		135.0		pF	Vds = 12.5 Vgs = 0V, F = 1 MHz
Crss	Common Source Feedback Capacitance		10.5		pF	Vds = 12.5 Vgs = 0V, F = 1 MHz
Coss	Common Source Output Capacitance		165.0		pF	Vds = 12.5 Vgs = 0V, F = 1 MHz

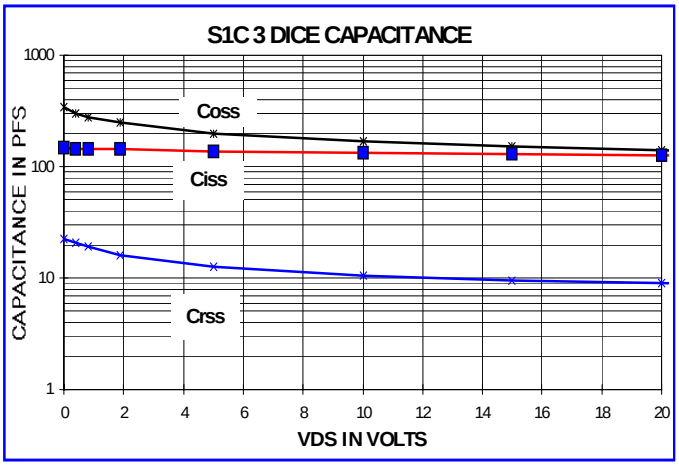
1110 Avenida Acaso, Camarillo, Ca 93012 Tel:(805) 484-4210 FAX: (805) 484-3393 EMAIL:Sell@polyfet.com URL:www.polyfet.com

SK723

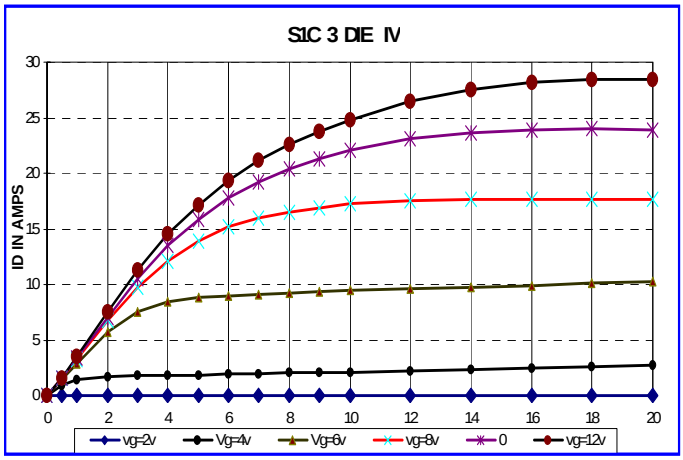
POUT VS PIN GRAPH



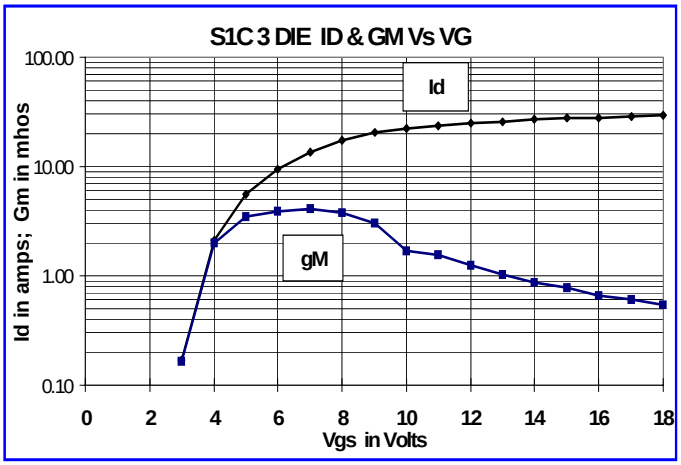
CAPACITANCE VS VOLTAGE



IV CURVE

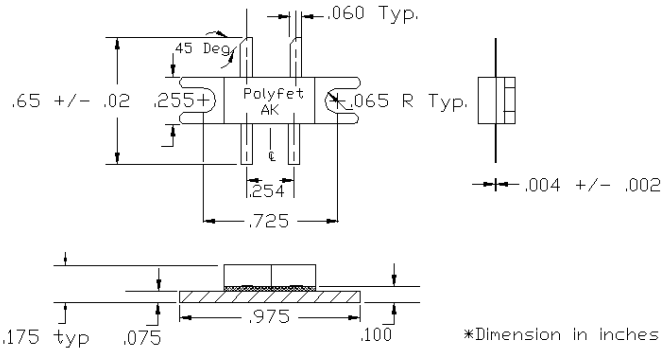


ID & GM VS VGS



Zin Zout

PACKAGE DIMENSIONS IN INCHES



Tolerance .XX +/-0.01 .XXX +/-.005 inches

POLYFET RF DEVICES

REVISION 03/16/2010

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